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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## $V_{\mathsf{R}}$ 650V $I_{\mathsf{F}}$ **A8**

# $\mathbf{Q}_{\mathbf{C}}$ 21nC

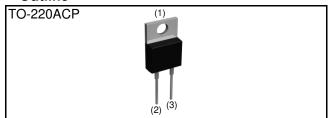
#### Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

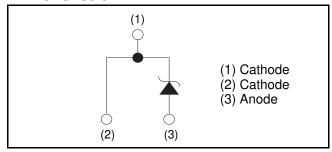
#### Construction

Silicon carbide epitaxial planar type

#### ●Outline



#### ●Inner Circuit



Packaging Specifications

	<u> </u>	
	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Type	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS308AH

#### ● Absolute Maximum Ratings (T<sub>i</sub> = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		$V_{RM}$	650	V
Reverse voltage (DC)		$V_R$	650	V
Continuous forward	current (T <sub>c</sub> =135°C)	l <sub>F</sub>	8	А
Surge non-	PW=10ms sinusoidal, T <sub>j</sub> =25°C		67	А
repetitive forward	PW=10ms sinusoidal, T <sub>j</sub> =150°C	I <sub>FSM</sub>	57	A
current	PW=10μs square, T <sub>j</sub> =25°C		250	А
Repetitive peak forward current		I <sub>FRM</sub>	36 * <sup>1</sup>	А
1≦PW≦10ms, T <sub>j</sub> =25°C		.∫ i²dt	22	A <sup>2</sup> s
i <sup>2</sup> t value 1≦PW≦10ms, T <sub>j</sub> =150°C		J I⁻dt	16	A <sup>2</sup> s
Total power disspation		$P_{D}$	57 * <sup>2</sup>	W
Junction temperature		T <sub>j</sub>	175	°C
Range of storage temperature		$T_{stg}$	-55 to +175	°C

<sup>\*1</sup> T<sub>c</sub>=100°C, T<sub>i</sub>=150°C, Duty cycle=10% \*2 T<sub>c</sub>=25°C

# ullet Electrical characteristics (T<sub>j</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
raiametei			Min.	Тур.	Max.	UIIIL
DC blocking voltage	$V_{DC}$	$I_R = 40 \mu A$	650	-	-	V
	V <sub>F</sub>	I <sub>F</sub> =8A,T <sub>j</sub> =25°C	-	1.35	1.50	V
Forward voltage		I <sub>F</sub> =8A,T <sub>j</sub> =150°C	-	1.44	1.71	V
		I <sub>F</sub> =8A,T <sub>j</sub> =175°C	-	1.50	-	V
	I <sub>R</sub>	V <sub>R</sub> =650V,T <sub>j</sub> =25°C	-	0.024	40	μΑ
Reverse current		V <sub>R</sub> =650V,T <sub>j</sub> =150°C	-	1.6	160	μΑ
		V <sub>R</sub> =650V,T <sub>j</sub> =175°C	-	4.8	-	μΑ
Total canacitance	С	V <sub>R</sub> =1V,f=1MHz	-	400	-	pF
Total capacitance		V <sub>R</sub> =650V,f=1MHz	-	36	-	pF
Total capacitive charge	$Q_{C}$	V <sub>R</sub> =400V,di/dt=350A/μs	-	21	-	nC
Switching time	t <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E <sub>ava</sub>	L=1mH	-	110	-	mJ

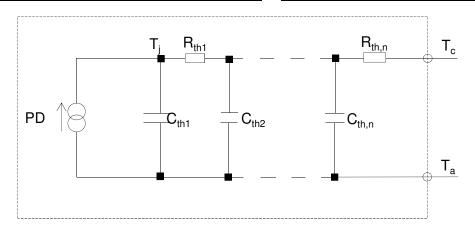
#### ●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
- Farameter			Min.	Тур.	Max.	Offic
Thermal resistance	R <sub>th(j-c)</sub>	-	-	1.8	2.6	°C/W

### ●Typical Transient Thermal Characteristics

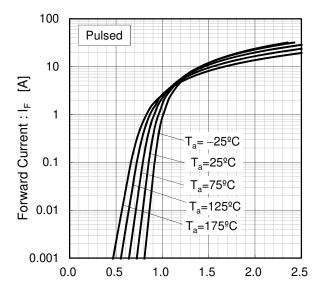
Symbol	Value	Unit
R <sub>th1</sub>	1.89E-02	
R <sub>th2</sub>	1.81E-01	K/W
R <sub>th3</sub>	1.55E+00	

Symbol	Value	Unit
C <sub>th1</sub>	1.95E-04	
C <sub>th2</sub>	8.01E-04	Ws/K
C <sub>th3</sub>	1.82E-03	



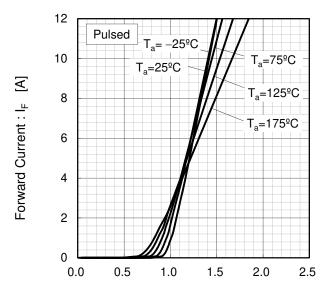
#### •Electrical characteristic curves

Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics



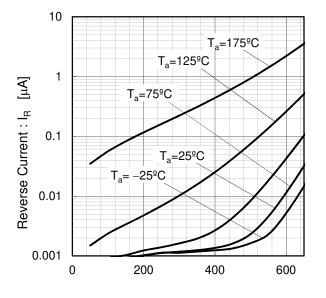
Forward Voltage : V<sub>F</sub> [V]

Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



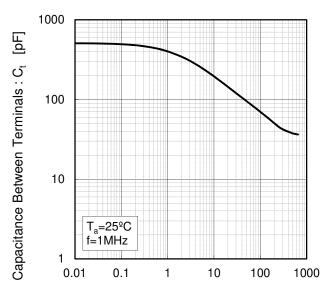
Forward Voltage : V<sub>F</sub> [V]

Fig.3  $V_R$  -  $I_R$  Characteristics



Reverse Voltage : V<sub>R</sub> [V]

Fig.4 V<sub>R</sub>-C<sub>t</sub> Characteristics



Reverse Voltage : V<sub>R</sub> [V]

#### •Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width

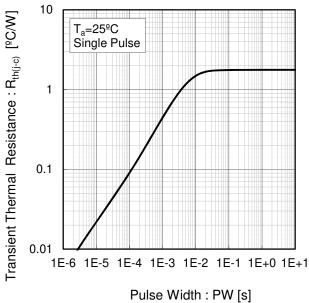
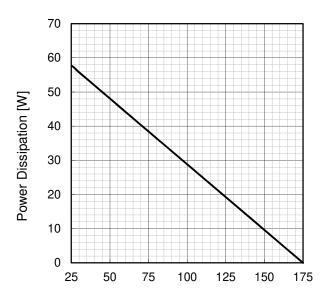
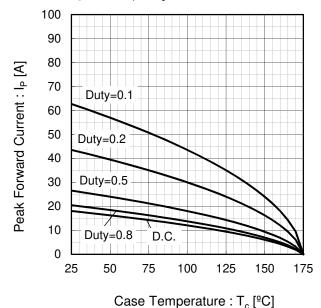


Fig.6 Power Dissipation



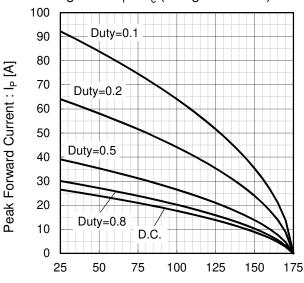
Case Temperature : T<sub>c</sub> [°C]

Fig.7\*3 Maximum peak forward current derating curve I<sub>P</sub> - T<sub>c</sub>



\*3 Based on max Vf, max  $R_{\text{th(j-c)}}$  Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8\*4 Typical peak forward current derating curve I<sub>P</sub> - T<sub>c</sub> (Not guaranteed)

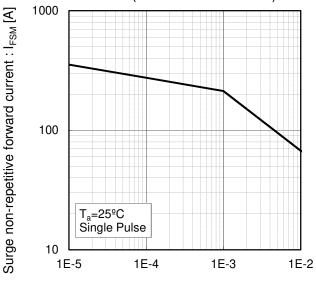


Case Temperature : T<sub>c</sub> [ºC]

\*4 Based on typ Vf, typ R<sub>th(j-c)</sub> Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

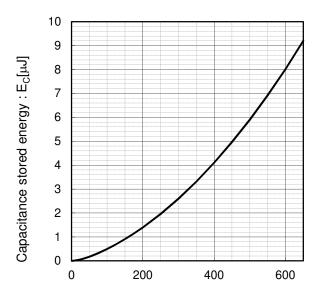
#### •Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



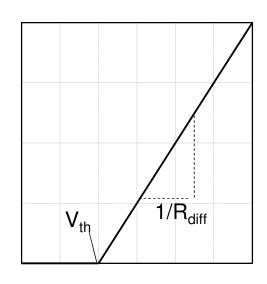
Pulse Width: PW [s]

Fig.10 Typical capacitance store energy



Reverse Voltage: V<sub>R</sub> [V]

Fig.11 Equivalent forward current curve



Forward Voltage: V<sub>F</sub>

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1}\,T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1}\,T_{j} + b_{2}\,T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit	
$a_0$	9.66E-01	٧	
a <sub>1</sub>	- 1.10E-03	V/°C	
$b_0$	4.40E-02	Ω	
b <sub>1</sub>	9.33E-05	Ω/°C	
b <sub>2</sub>	9.60E-07	Ω/°C <sup>2</sup>	

 $T_{j}$  in  ${}^{\circ}C$ ; -55  ${}^{\circ}C$  <  $T_{j}$  < 175 ${}^{\circ}C$  ;  $I_{F}$  < 16A

Forward Current : I<sub>F</sub>

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# SCS308AHG - Web Page

**Distribution Inventory** 

Part Number	SCS308AHG
Package	TO-220ACP
Unit Quantity	1000
Minimum Package Quantity	50
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes